TOSHIBA Field Effect Transistor Silicon P-Channel MOS Type (U-MOS III)

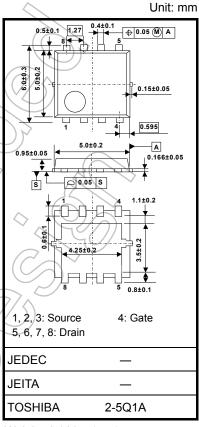
TPCA8104

High-Side Switching Applications Portable Equipment Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance: RDS (ON) = 11 m Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 50 \text{ S (typ.)}$
- Low leakage current: $IDSS = -10 \mu A (max) (VDS = -60 V)$
- Enhancement mode: $V_{th} = -0.8$ to -2.0 V ($V_{DS} = -10$ V, $I_{D} = -1$ mA)

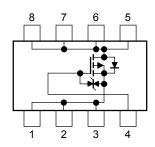
Absolute Maximum Ratings (Ta = 25°C)

Characteristic			Symbol	Rating	Unit
Drain-source voltage			V_{DSS}	-60	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)			V _{DGR} <	-60	
Gate-source voltage			V _{GSS}	±20	<\v
Drain current	DC	(Note 1)	ID((-40	A
Diam current	Pulse	(Note 1)	IDP	-120	Α `
Drain power dissipation (Tc = 25°C)		((PD)	45		
Drain power dissipation (t = 10 s) (Note 2a)			PD	2.8	W
Drain power dissipation (t = 10 s) (Note 2b)			PD	1.6	\rightarrow
Single-pulse avalanche energy (Note 3)		E _{AS} 116		mJ	
Avalanche cur	rent		IAR	-40	Α
Repetitive avalanche energy (Tc = 25°C) (Note 4)		E _{AR}	4.5	mJ	
Channel temperature		Tch	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	



Weight: 0.080 g (typ.)

Circuit Configuration



Note: For Notes 1 to 4, see the next page.

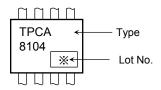
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.

Thermal Characteristics

Characteristic	Symbol	Max	Unit	
Thermal resistance, channel to case (Tc = 25°C)	R _{th (ch-c)}	2.78	°C/W	
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th (ch-a)}	44.6	°C/W	
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	78.1	C/VV	

Marking (Note 5)



Note 1: The channel temperature should not exceed 150°C during use.

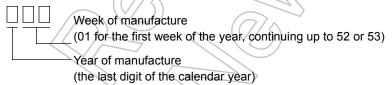
Note 2: (a) Device mounted on a glass-epoxy board (b) Device mounted on a glass-epoxy board (b)



Note 3: $V_{DD} = -24 \text{ V}$, $T_{Ch} = 25^{\circ}\text{C}$ (initial), L = 0.1 mH, $R_G = 25 \Omega$, $I_{AR} = -40 \text{ A}$

Note 4: Repetitive rating: pulse width limited by maximum channel temperature.

Note 5: * Weekly code (three digits):



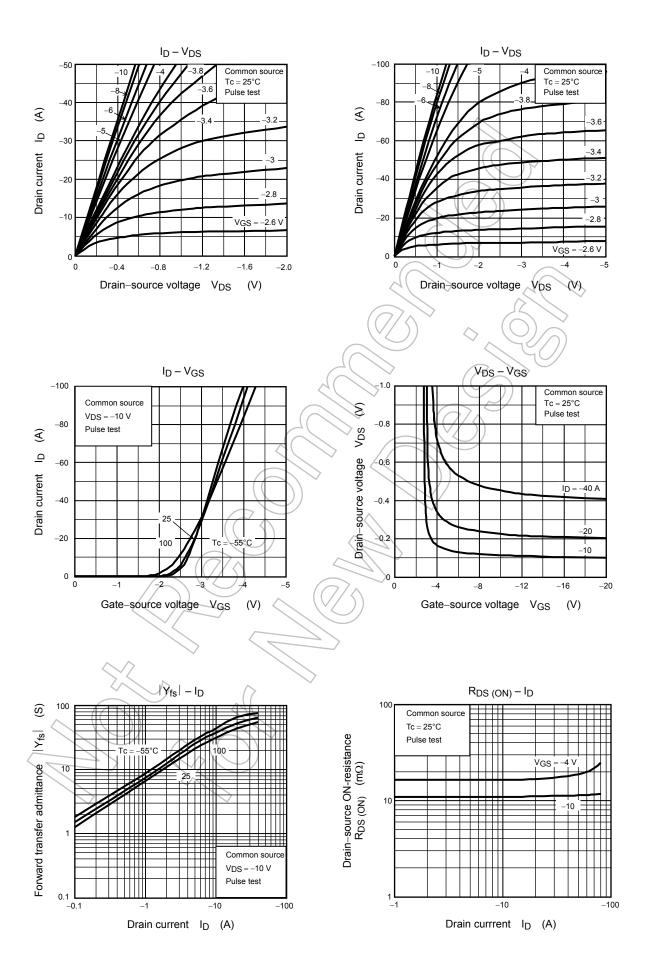


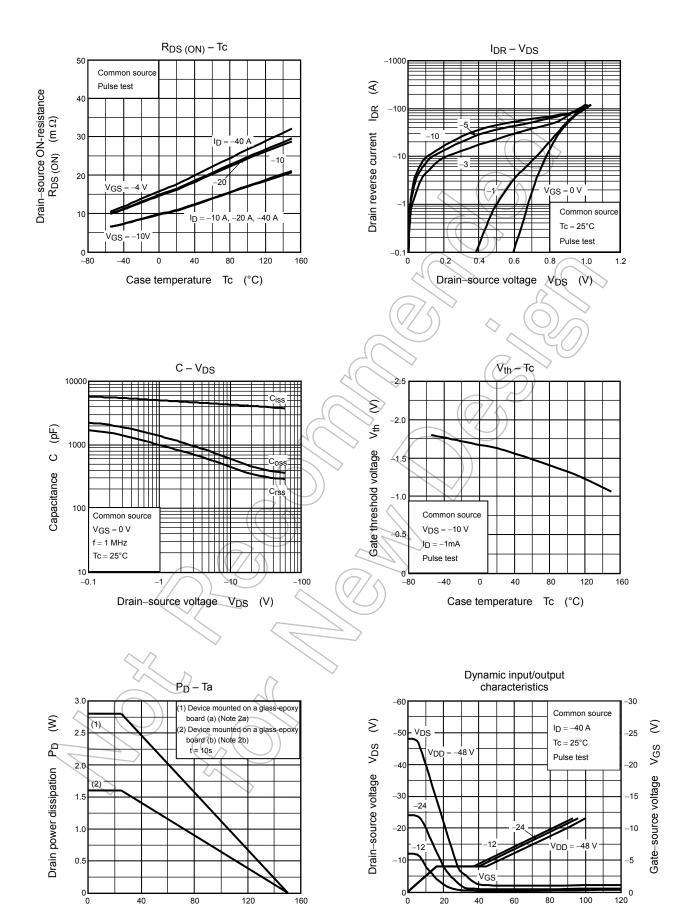
Electrical Characteristics (Ta = 25°C)

Cha	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curi	rent	I _{GSS}	V _{GS} = ±16 V, V _{DS} = 0 V	_	_	±10	μΑ
Drain cutoff curre	nt	I _{DSS}	V _{DS} = -60 V, V _{GS} = 0 V	_	_	-10	μΑ
Drain-source breakdown voltage		V _{(BR)DSS}	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-60	_		V
		V _{(BR)DSX}	$I_D = -10 \text{ mA}, V_{GS} = 20 \text{ V}$	35	/	_	v
Gate threshold vo	ltage	V _{th}	V _{DS} = -10 V, I _D = -1 mA	0.8))′_	-2.0	V
Drain-source ON-resistance		Б	V _{GS} = -4 V, I _D = -20 A) / /	17	24	mΩ
		R _{DS} (ON)	V _{GS} = -10 V, I _D = -20 A	\mathcal{A}	11	16	
Forward transfer	admittance	Y _{fs}	V _{DS} = -10 V, I _D = -20 A	25	50		S
Input capacitance		C _{iss}		_	4300		
Reverse transfer capacitance		C _{rss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	450	_	pF
Output capacitance		Coss		_ /	600	\searrow	
Switching time	Rise time	t _r	V _{GS} = -20A Output V _{DD} ≈ -30 V	_(10	<u> </u>	
	Turn-on time	t _{on}		7	20	_	20
	Fall time	t _f			60	_	ns
	Turn-off time	t _{off}	Duty \leq 1%, $t_W = 10 \mu s$) _	200	_	
Total gate charge (gate-source plus gate-drain)		Qg	V _{DD} ≈ -48 V, V _{GS} = -10 V	_	90	_	
Gate-source charge 1		Q _{gs1}	I _D = -40 A	_	16	_	nC
Gate-drain ("Miller") charge		Q _{gd}		_	28		

Source-Drain Ratings and Characteristics (Ta = 25°C)

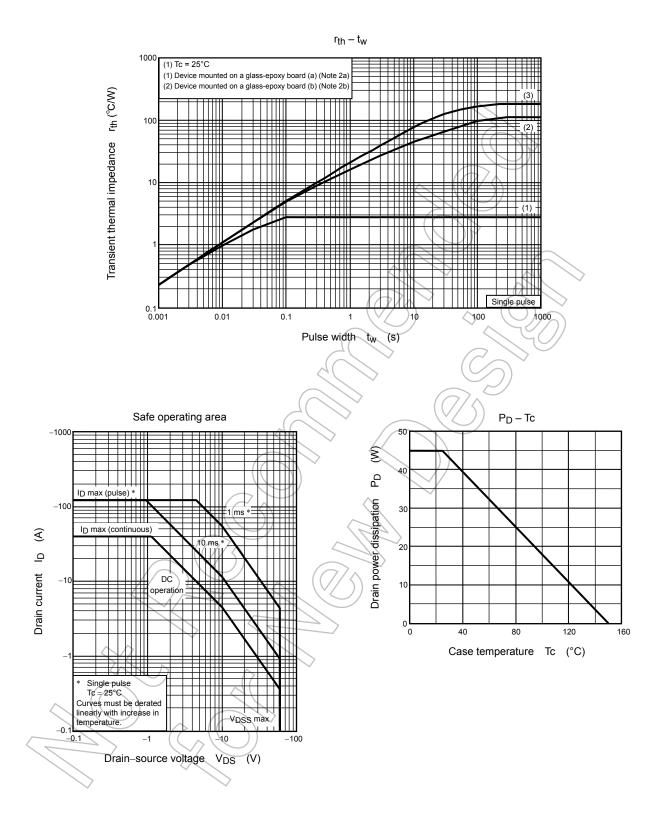
Characteristic		Symbol Test Condition		Min	Тур.	Max	Unit
Drain reverse current	Pulse (Note 1)	DRP	_	_	_	-120	Α
Forward voltage (diode)		V_{DSF} $I_{DR} = -40 \text{ A}, V_{C}$	GS = 0 V	_	_	1.2	V





Ambient temperature Ta (°C)

Total gate charge Q_g (nC)



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